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Application Number	10/621,120	
Filing Date	July 16, 2003	
First Named Inventor	Chih Yuan Huang	
Group Art Unit	2818	
Examiner Name	Andy Huynh	
Attorney Docket Number	MXIC 1532-1	

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Examiner Initials	Cite No.1	U.S. Patent Document  Kind Code² (if known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
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Examiner Initials		Office <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>s</sup> ( <i>if known</i> )	Applicant of Cited Document	Cited Document MM-DD-YYYY	Passages or Relevant Figures Appear	T <sup>6</sup>
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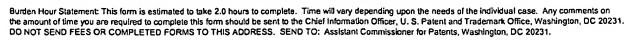


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	(use as many sheets as necessary)				Examiner Name	Andy Huynh		
	Sheet		of	2	Attorney Docket Number	MXIC 1532-1		

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